How Deposition Parameters Affect Phase Formation in Metals

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Abstract: To understand the mechanism for formation of fcc-cobalt nanowires in electrodeposition, we have systematically studied the effect of deposition potential, pH, and deposition temperature on the formation of fcc Co nanowires by X-ray diffraction (XRD), transmission electron microscope (TEM) and scanning electron microscope (SEM). The Co nanowires deposited at the potential of -1.6V are pure hcp phase. When increasing the value of potential to -2.0V, there are hcp Co and fcc Co crystals in the deposited nanowires. The fraction of fcc Co crystals in the nanowires increases with increasing the potential value. At -3.0V, the nanowires are pure fcc Co. The pH of the solution has little effect on formation of fcc Co nanowires. We have also seen that high concentration and low temperature favors fcc phase whereas low concentration and high temperature favors hcp phase. However, at 35°C the co-occurrence of hcp and fcc phases were also observed. These experimental results can be explained by the classical electrochemical nucleation theory. The formation of fcc Co crystals can be attributed to smaller critical clusters formed at a higher potential value since the smaller critical clusters favor formation of fcc nuclei.

Keywords: Nanostructure, Electrodeposition, Fcc Cobalt, Crystal Growth

1. Introduction

The metallic cobalt (Co) is an hcp (hexagonal close packing) phase at temperatures below 420°C and an fcc (face-centered cubic) phase at temperatures above 420°C. However, the high temperature phase, fcc Co, can be formed in electrodeposition at ambient temperature. [1-3] A lot of studies have been done on experimental conditions of forming fcc Co in electrodeposition at ambient temperature. These studies show that the formation of fcc Co is favored at lower pH of electrolyte [1, 4-7] and at higher potentials. [2, 8, 9] Studies on the mechanism of forming fcc Co in electrodeposition. During the process of electrodeposition, by adjusting deposition conditions such as the pH value [10], pulse electrodeposition [11, 12], deposition potential [13], deposition current density [14], and deposition temperatures [15], the microstructure of Co nanowire was adjusted accordingly. However, have not received much attention and only a few reports are found on

the dependence of crystal orientation of cobalt nanowires with bath temperature [16], and electrolyte concentration [17]. For example, Nakahara and Mahajan argued: [1] metastable fcc Co hydride could form during electrodeposition at low pH; after the deposition, the fcc Co hydride phase can be decomposed and partially transformed to hcp Co because of the rapid out-diffusion of hydrogen. This can explain their experimental observation that the Co film prepared at low pH contains not only fcc Co but also hcp Co. [1] Studies of Wang et al [8] and Huang et al [9] show that the single crystalline Co nanowires are hcp phase at the lower deposition potential of about -1.5 V, and fcc phase at the higher deposition potential of -3.0 V. Cohen-Hyams et al also observed fcc Co in the film deposited at high potentials. [2] Wang et al, [8] Huang et al [9] and Cohen-Hyams et al [2] explained the formation of fcc Co using the view of Nakahara and Mahajan. [1] We disagree with the view of Nakahara and Mahajan, based on three reasons. First, XRD results obtained by Wang et al and Huang et al show that the nanowires deposited at -3.0 V are pure fcc

Co, [8, 9] indicating that no decomposition of fcc Co hydride phase into hcp Co phase occurs. This cannot be explained by the model proposed by Nakahara and Mahajan. [1] Second, a lot of TEM (transmission electron microscope) and XRD (X-ray diffraction) studies on the Co fine particles prepared by the vacuum deposition (vapor and sputtering depositions) show that the structure of Co fine particles depends on their sizes. [18-22] The Co particles are fcc structure for smaller sizes and hcp structure for larger sizes. [19, 22] Third, there is only a very small amount of hydrogen molecules in the vacuum chamber for deposition of Co particles. This indicates that hydrogen plays no role in forming fcc Co particles in vacuum deposition.

In this paper, an alternative explanation of why fcc Co nanowires form in electrodeposition at ambient temperature can be seen. Firstly, some systematic results about the effect of deposition potential, pH, deposition temperature and electrolytic cell concentration on the crystal structure of Co nanowires are discussed and then account for why Co nanowires are hcp structure at a lower potential value and fcc structure at a higher potential value and also show that how phase changes from fcc to hcp Co with respect to concentration and temperature.

2. Experimental Details

The detailed experimental procedure for preparation of the porous anodic alumina oxide (AAO) templates has been given in our previous paper. [23] Here we briefly describe the experimental procedure. Firstly, high-purity aluminum foils (99.999%) were degreased in acetone and then were annealed in a vacuum of 10^{-5} Torr at 500°C for 5 h to remove the mechanical stress. Secondly, the aluminum foils were anodized in a 0.3 M $\text{H}_2\text{C}_2\text{O}_4$ solution at 2°C for 6 h. After removing the alumina layer formed in the anodization in a mixture of phosphoric acid (6 wt%) and chromic acid (1.8 wt%), the aluminum foils were anodized again at the same conditions as the first anodization for 12 h. The templates that experienced the above two-step anodization were etched in a saturated CuCl_2 solution to remove the remaining aluminum on the back side. Thirdly, the alumina barrier layer was then dissolved in a 5 wt% phosphoric acid solution at 40°C . The templates obtained by the above method have the cylindrical and hexagonally arranged pores of about 50 nm in diameter. Finally, a gold (Au) film was sputtered onto the back side of the templates to serve as the working electrode.

The electrolyte used in this study was a mixture of $\text{CoSO}_4 \cdot 7\text{H}_2\text{O}$ having three different concentrations (0.71M, 0.53M, and 0.35M) and H_3BO_3 (0.68M) in aqueous solutions. Direct current electrodeposition was conducted in a two-electrode cell under different deposition potentials, pH, temperature and concentration respectively. The area of the working electrode for growth of nanowires was 0.608cm^2 ($=0.25\pi(0.88\text{cm})^2$) and the area of the graphite counter electrode was 14.7cm^2 ($=4.2\text{cm} \times 3.5\text{cm}$). The adjustment of pH of the electrolyte was done by adding 1 M H_2SO_4 solution.

The Co nanowires were analyzed by X-ray diffraction

(XRD, Y-2000) with CuK_α radiation ($\lambda = 0.154178\text{ nm}$). Before XRD measurements the sputtered Au film was mechanically polished away. The deposited Co nanowires were also analyzed by scanning electron microscope (SEM, JEOL JSM-6700F) and transmission electron microscope (TEM, JEOL JEM-2010). In order to perform SEM observations, the AAO template was partly dissolved with a 5 wt% NaOH solution, and then carefully rinsed with deionized water for several times. For TEM observations, the AAO was completely dissolved in a 5 wt% NaOH solution, then rinsed with deionized water several times, and finally dispersed in absolute ethanol by ultrasonic.

3. Results

3.1. For Deposition Potential and pH

Fig. 1 show the XRD patterns of Co nanowires deposited in the solution with a pH of 2.5 at four different potentials of -1.6, -2.0, -2.5 and -3.0V. The XRD data were collected from the top side of nanowires. The nanowires of Co prepared at -1.6V have a strong peak at $2\theta = 41.6$ degrees and this peak can be

unambiguously attributed to the hcp Co $(10\bar{1}0)$ plane diffraction. The nanowires of Co prepared at -3.0V have a strong peak at $2\theta = 75.6$ degrees.

Figure 1. XRD patterns of Co nanowires deposited at different potentials: (a) -1.6V, (b) -2.0V, (c) -2.5V, (d) -3.0V.

The peak at $2\theta = 75.6$ degrees is difficult to index from

XRD measurements since the hcp Co (11 $\bar{2}$ 0) and fcc Co (220) planes have the same diffraction peak position at $2\theta = 75.6$ degrees. Since single crystal electron diffraction pattern can be used to distinguish crystal structure, [24] we have

performed TEM observations on the Co nanowires deposited at -3.0V in order to identify this peak. Fig. 2 gives the TEM image and electron diffraction pattern of a Co nanowire deposited at -3.0V.

Figure 2. TEM image (a) and electron diffraction pattern (b) of a Co nanowire deposited in the solution of pH 2.5 at -3.0 V.

Figure 3. XRD patterns of fcc Co nanowires deposited at -3.0V in the solutions of pH 4.0 and pH 6.0.

The observed electron diffraction pattern is the same as the standard fcc crystal diffraction pattern in the case of the incident electron beam direction being $\langle 110 \rangle$. Moreover, the observed ratio of the spot spacings of L to M (1.163) is in

agreement with the ratio ($2/\sqrt{3} = 1.155$) in the standard diffraction pattern. Therefore, the Co nanowires deposited at -3.0V are an fcc phase. Our TEM results are in agreement with those obtained by Wang et al [8] and Huang et al [9]. Using HRTEM, Wang et al and Huang et al have demonstrated that the nanowires of Co deposited at -3.0V are fcc single crystalline, thus attributing the peak at $2\theta = 75.6$ degrees to the diffraction of fcc (220) plane. After indexing the peak at $2\theta = 75.6$ degrees, the effect of deposition potentials on the formation of fcc Co can be seen. It can be seen from Fig. 1 that the nanowires deposited at -1.6V are pure hcp Co. The Co nanowires deposited at -2.0V contain hcp and fcc crystals; and the fraction of hcp crystals is much more than that of fcc crystals. The fraction of fcc crystals increases with increasing the potential value. The Co nanowires deposited at -3.0V are pure fcc Co.

Previous studies show that, in the case of the electrodeposited Co films, low pH (<2.4) favors formation of fcc Co while high pH (>2.9) favors hcp Co. In order to understand the effect of pH on the formation of fcc Co nanowires, Co nanowires deposited at -3.0V in the solution of pH 4.0 and pH 6.0, respectively. Fig. 3 shows the XRD patterns of Co nanowires deposited at -3.0 V in the solution with pH of 4.0 and 6.0. No peak was observed due to the hcp Co on the patterns, indicating that the pH of the solution has little effect on the formation of fcc Co nanowires at the Au-coated AAO template for the pH range studied.

In order to get a complete understanding of the effect of deposition potential and pH on formation of Co nanowires, experimental results of Co nanowires, which were obtained by other researchers and us, are aggregated into Table 1. One can see three points from Table 1. First, high (low) deposition potential favors formation of fcc (hcp) Co nanowires. Second, the pH effect does not occur in deposition of Co nanowires.

Third, the experimental observations of forming fcc Co nanowires at high pH (4.0-6.5) cannot be explained by the mechanism of Nakahara and Mahajan.

Table 1. The effect of deposition potential and pH on crystal structure of Co nanowires. S represents the single-crystalline and P the polycrystalline.

Co nanowires	deposition potential (or current density)	pH	references
Pure hcp Co (S)	-1.5V, -1.45V	4.0, 5.5	Huang et al, [9] Wang et al [8]
Pure fcc Co (S)	-3.0V	2.0, 5.5	Huang et al, [9] Wang et al [8]
Pure fcc Co (P)	2.5 or 40 mA/cm ²	3.0, 6.0, 6.5	Cho et al [25]
Pure hcp Co (S)	-1.6V	2.5	this work
Pure fcc Co (S)	-3.0V	2.5, 4.0, 6.0	this work

Fig. 4 displays SEM images of Co nanowires deposited at -1.6 V in the solution of pH 2.5 (Fig. 4a) and at -3.0V in the solution of pH 4.0 (Fig. 4b) and pH 6.0 (Fig. 4c) separately.

Figure 4. SEM images of Co nanowires deposited at -1.6 V and pH 2.5 (a), at -3.0 V and pH 4.0 (b), at -3.0 V and pH 6.0 (c).

The diameter of the Co nanowires (~50nm) is the same as that of the pores of AAO template (~50nm), indicating that the cylindrical pores of the AAO template were fully filled with Co atoms during electrodeposition.

3.2. For Deposition Temperature and Electrolytic Cell Concentration

Fig. 5 shows the XRD patterns of Co nanowires deposited in the solution with concentration of 0.71M at pH of 2.5 and at six different temperatures (5°C, 15°C, 25°C, 35°C, 45°C, and 60°C) under deposition potential of -3V.

The XRD patterns were collected from the top side of nanowires. The coexistence of both hcp and fcc cobalt phases were seen. It is found that the crystal structure of Co nanowires lies on the deposition conditions. When electrodeposition is performed in a same electrolytic cell but at different temperatures, the phase changed from fcc (at low temperature) to hcp (at high temperature). Fig. 5 (a, b, and c) represent that at low temperatures 5°C, 15°C, and 25°C, the well-known fcc structure of Co has been deposited, respectively, which is stable at temperatures above 422°C [10], while increasing the temperature to 35°C-60°C both hcp and fcc structures exist there (see Fig. 5 (d and e)). From the figure one can also observe at 25°C the phase for deposited Co nanowires is fcc and result agreed with the result of wang et al and Huang et al [13, 26].

Figure 5. XRD pattern for electrochemically deposited Co nanowires in the pores of AAO template at different temperatures having concentration of 0.71M, a) 5°C b) 15°C, c) 25°C d) 45°C, and e) 60°C.

Fig. 6 illustrates the XRD patterns of Co nanowires deposited in electrolytic cell having solution with concentration of 0.53M (cobalt sulfate) and pH of 2.5. The deposition is performed at five different temperatures (15°C, 25°C, 35°C, 45°C, and 60°C) at deposition potential of -3V. From the Fig. 6 (a, c, d, and e), the fcc structure is seen at low temperature of 15°C and 25°C, while the universal hcp structure for the electrodeposited Co is obtained at temperatures of 45°C, and 60°C, respectively.

Figure 6. XRD pattern for electrochemically deposited Co nanowires in the pores of AAO template at different temperatures having concentration of 0.53M, a) 15°C b) 25°C, c) 35°C d) 45°C, and e) 60°C.

At temperature of 35°C the coexistence of hcp ($10\bar{1}0$), (002) and fcc (220) diffraction peaks present that phase is being changed (see Fig. 6 (b)).

To find out the concentration effect with change in temperature Co nanowires were also deposited in a cell containing 0.35M concentration of cobalt sulfate at pH of 2.5. XRD results for this cell at four different temperatures (25°C, 35°C, 45°C, and 60°C) are presented in Fig. 3. From the Fig. 7 (a) the diffraction peaks at $2\theta = 41.5$, and 75.6 degrees confirm the existence of hcp and fcc structure at temperature 25°C. At temperature 35°C there is a little increase in the intensity of ($10\bar{1}0$) which shows that some nanowires grow along $[10\bar{1}0]$ direction and others along $[220]$ direction. It can be seen from the Fig. 7 (c, and d) that further increases in temperature give the pure hcp phase. There is only a single

peak along ($10\bar{1}0$) plane, which indicates the pure hcp structure and well-preferred growth of Co nanowires along $[10\bar{1}0]$ direction at temperatures of 45°C, and 60°C.

Figure 7. XRD pattern for electrochemically deposited Co nanowires in the pores of AAO template at different temperatures having concentration of 0.35M, a) 25°C, b) 35°C, c) 45°C, and d) 60°C.

In order to understand the effect of solution concentration and the deposition temperature, the X-ray diffraction results are gathered in Table 2. From the table one can see three points. Firstly, the structure of the deposited Co nanowires is fcc at low temperature ($<25^\circ\text{C}$) for all concentrations. Secondly, for all concentrations high temperatures ($> 25^\circ\text{C}$) favor the growth in hcp phase. Moreover, higher temperature favors hcp phase while higher concentration favors fcc phase.

4. Discussion

From the dependence of the Co crystal structure on the size of a Co nucleus, we can obtain insight into the mechanism of forming fcc Co in electrodeposition. In the following, first explain the dependence of the Co crystal structure on the size of Co nucleus and then elucidate the mechanism for formation of fcc Co crystals in electrodeposition at ambient temperature.

4.1. The Dependence of the Crystal Structure of Co Nucleus on Its Size

The total free energy of a crystal nucleus is the sum of the bulk free energy and surface free energy of the nucleus. The bulk free energy of hcp Co (G_{hcp}) is lower than that of fcc Co

(G_{fcc}) at temperatures below 420°C. The difference between G_{hcp} and G_{fcc} is of the order of 10^6 J/m³. [22, 27] However, the surface energy density of hcp Co phase is higher than that of fcc Co phase. [22, 28, 29] At temperatures below 420°C, therefore, the crystal structure of Co nucleus can depend on the size. When the size of a Co nucleus is very small, the fcc structure can be thermodynamically more stable than the hcp structure due to the significant surface effect. This has been confirmed by the many experimental observations that Co particles with very small sizes are fcc phase. [20, 21, 30, 31] For example, when sputtering Co onto a substrate under a low argon gas pressure of 0.15 Torr, Co particles grown on the substrate are fcc structure. TEM results show that these fcc Co particles have sizes of 10-20 nm. [19, 22] However, when sputtering Co in a higher argon gas pressure, hcp-Co particles are obtained. TEM results show that these hcp-Co particles have sizes of 40-50 nm. [19, 22] These experimental results can be explained as follow. In the former case, smaller nuclei of fcc Co form. Once the smaller nuclei of fcc Co form, they grow into smaller fcc Co particles (10-20 nm). In the latter case, larger nuclei of hcp Co form, they grow into larger hcp Co particles (40-50nm). From the above arguments, it is clear that a larger Co nucleus favors an hcp structure while a smaller Co nucleus favors an fcc structure.

4.2. The Effect of Deposition Potentials and pH on the Crystal Structure of Co

In the electrodeposition for formation of metal nanowires, hydrated metal ions in solution arrive at the surface of a metal and are neutralized by electron tunneling, forming neutral adatoms at the surface. [23] These adatoms can move and form a cluster of N adatoms. According to the classical electrochemical nucleation theory, the free energy of formation of a 3 dimension cluster of N adatoms, $\Delta G(N)$, is given by [32, 33].

$$\Delta G(N) = -Nze\eta + bN^{\frac{2}{3}} \quad (1)$$

where z is the valence of the hydrated metal ions, e is the elementary electric charge, η is the overpotential, b is the constant depending on the geometrical shape of the cluster. Taking the derivative of Eq. (1) with respect to N and equating to zero yields the size of the critical cluster, N_c

$$N_c = \left(\frac{2b}{3ze\eta} \right)^3 \quad (2)$$

From eq. (2), it can be seen that the size of the critical cluster N_c depends on both overpotential (η) and the geometrical shape of the cluster (b). The size of the critical cluster decreases with increasing the overpotential. The physical meaning of the critical cluster is that the critical cluster can be either transformed into a crystal nucleus for growth if gaining one atom or dissolved if losing one atom. [33] Before transformation into a crystal nucleus, the structure of the critical cluster can be like amorphous and not well defined.

The formation of clusters of Co atoms occurs on a polycrystalline Au surface. The surface structure of the polycrystalline Au is not smooth but geometrically irregular in the nanoscale. This leads to clusters formed on the Au surface having various shapes. It can therefore be seen from eq.(2) that the sizes of the critical clusters N_c formed under a fixed deposition potential should have a distribution because of different shape factors (b). At the low potential of -1.6 V, the sizes of all critical clusters, which are determined by eq. (2), are large. This favors formation of the large crystal nuclei of hcp Co for the growth. As a result, pure hcp Co nanowires were observed. When the potential value increases to -2.0V, the size distribution of critical clusters shifts to small sizes, in which a small fraction of critical clusters is small in size enough to form crystal nuclei of fcc Co. Thus, a small fraction of fcc Co crystals formed in nanowires. For deposition at -2.5V, the fraction of fcc Co nuclei increases relatively since the size distribution of critical clusters shifts further to smaller sizes; so the fraction of Co fcc crystals formed at -2.5V increases relatively. At deposition at -3.0V, the sizes of all the critical clusters is in the range of forming fcc Co nuclei and therefore pure fcc Co nanowires were observed.

The pH effect can also be explained by the mechanism described above. The environment of nucleation sites for deposition of Co films is significantly different from that of Co nanowires. The size of metal grains in the substrate for deposition of Co films is of the order of micrometers. The sizes of facets of the grains are also of the order of micrometers. The surface of the substrate consists of two parts: (1) the areas located in boundaries of grains, and (2) the areas located in facets of grains. Since the areas of facets are dominated over the surface, nucleation of Co atoms can occur mainly on the facets. A positively charged hydrogen ion within an acidic electrolyte solution is hydrated, forming a hydroxonium ion H_3O^+ . The hydroxonium ion in the bulk of the solution can diffuse to the cathodic surface where neutralization (dehydration) occurs by electron tunneling from the cathodic metal surface to hydroxonium ion, forming the neutral hydrogen atom. [33] The produced hydrogen atoms can be divided into four parts. First, hydrogen atoms can be incorporated into lattice. This part is an extremely small fraction as the probability of hydrogen dissolved into the lattice is extremely small. [1] Second, hydrogen atoms can be incorporated into grain boundaries as the grain boundaries, in which the metal atoms are loosely packed, have much space to accommodate hydrogen atoms. Moreover, the hydrogen can penetrate through the substrate by diffusing along the grain boundaries and desorb into air; and this can be understood by the experimental observation that the hydrogen in air can penetrate through the stainless steel wall of the vacuum chamber and go into the chamber. However, this part is also a very extremely fraction because of the very extremely volume of grain boundary regions compared to the lattice volume. Third, the hydrogen atoms can recombine to form adsorbed hydrogen molecules, which can desorb from the deposited surface as bubbles. Fourth, hydrogen atoms can occupy the surface sites and impede Co atoms from diffusing to

nucleation sites when hydrogen atoms are large in number. [34] This can have an effect on the shape and size of clusters. In the case of low pH, hydrogen atoms at the surface can be large in number enough to impede Co atoms from diffusing to nucleation sites, as shown in Fig. 8. These H adatoms can change the shape of clusters and reduce the size of clusters, which can lead to formation of smaller clusters and so fcc Co nuclei. Therefore low pH favors formation of fcc Co films.

Figure 8. Schematic illustration of the effect of H adatoms on the shape and size of Co clusters. The shape and size of the cluster formed at site A is different from that at site B. Not drawn to scale.

For deposition of Co nanowires, however, nucleation occurs on the sputtered Au film, which consists of Au nanoparticles. There are much more grain boundaries in the Au film than in the substrate for deposition of Co film. For the sputtered Au film, the volume of grain boundary regions is appreciable due to the significant surface effect, compared to that of lattice. Moreover, the thickness of Au film is small (about 150-200nm). In this case, a lot of hydrogen adatoms can quickly go into the grain boundaries, then penetrate through the thin Au film by diffusing along the grain boundaries and desorb into air, as argued above. As a result, H adatoms on the surface of Au film can be significantly reduced in number so that cannot impede Co atoms from diffusing to nucleation sites. Thus, hydrogen atoms cannot influence the shape and size of clusters and therefore no pH effect occurs in deposition of Co nanowires.

The fcc Co nanowires of 50nm in diameter can be metastable with respect to the hcp Co nanowires at room temperature. This means that the free energy of the fcc Co nanowires can be higher than that of the hcp Co nanowires. However, the transformation from fcc phase to hcp phase requires overcoming an energy barrier and thermal energy at room temperature is too small to activate the transformation. The fcc structure of Co nanowires therefore remain unchanged

at room temperature.

4.3. The Effect of Deposition Temperature and Electrolytic Cell Concentration on the Crystal Structure of Co

When electrodeposition originates, nucleation must arise. This situation is just related to the nucleation which happens in a supersaturated solution [35]. Here an ion go into the diffusion layer, dehydrated, and after discharging it must diffuses and ultimately form a nucleus by linking other ad-atoms. The nucleation rate depends on the average number of critical clusters (n) and the diffusion of molecules to the cluster (β), is given by the equation

$$I = n\beta \quad (3)$$

The average population of the critical nuclei is given by the relation

$$n \propto \exp(-\Delta G/k_B T) \quad (4)$$

Where ΔG is the critical free energy needed corresponding to that of critical nucleus, k_B is the Boltzmann constant, and T is the temperature. The number of clusters of a certain size formed is a function of the total number of atoms in the system, the free energy to create a cluster, and the temperature. The number of clusters increases with increasing temperature. The crystal structure of Co nucleus can depend on the size. When the size of a Co nucleus is very small, the fcc structure can be thermodynamically more stable than the hcp structure due to the significant surface effect. Many researches confirmed by experimental observations that Co particles with very small sizes are fcc phase [20, 21, 30, 31]. From the relation the nucleation probability will be high if temperature of electrolyte is increased. On the higher nucleation rate the size of the nucleus is small which results in the hcp phase as discussed above. The same phenomenon is seen in our case, higher temperature causes the higher nucleation rate result into hcp phase and lower temperature favor the smaller nuclei to form fcc Co. It is clear from the above arguments that a larger Co nucleus favors an hcp structure while a smaller Co nucleus favors an fcc structure.

Similarly the impact of the electrolyte concentration on the morphology and on the configuration of the deposited Co nanowires is illustrated in Table 2. The conclusions, which observed upon equating the variations in the surface morphology and the structure of the deposited cobalt coatings, are the following: As concentration of electrolyte is increased, the size of the growing cobalt nucleus is decreased which means we get fcc phase considerably. We also find the coexistence of both hcp and fcc phases for Co nanowires at different concentration but at different temperature for each concentration. It means temperature and concentration effect are interlink.

Table 2. XRD results for all concentrations and temperatures presenting the phase change.

Concentrations	Temperatures					
	5°C	15°C	25°C	35°C	45°C	60°C

Concentrations	Temperatures					
	5°C	15°C	25°C	35°C	45°C	60°C
0.71M	fcc	fcc	fcc	hcp and fcc	hcp and fcc	hcp and fcc
0.53M	-	fcc	fcc	hcp and fcc	hcp	hcp
0.35M	-	-	hcp and fcc	hcp and fcc	hcp	hcp

5. Conclusions

The formation of fcc Co nanowires depends mainly on the deposition potential. Crystals of fcc Co appear in the nanowires at -2.0V and the fraction of fcc Co crystals increases with increasing the deposition potential; and at -3.0V the nanowires are pure fcc Co. It is also concluded that growth orientation of Co nanowires prominently depends on the electrolytic concentration and temperature. When the concentration of electrolytic cell is high, fcc Co structure is dominant in XRD results at nearly room temperature (25°C) and below, whereas at low concentration this dominance of fcc Co structure is gradually decreased. It has also been seen that under low temperature of electrolytic cell of different concentration Co nanowires exhibits fcc phase, however fcc phase changes to hcp phase when temperature is increased. Simply, high concentration and low temperature of electrolytic cell favor fcc phase whereas low concentration and high temperature favor hcp phase of Co nanowires. The pH of the solution has little effect on formation of fcc Co nanowires. The formation of fcc Co crystals can be attributed to smaller critical clusters formed at higher deposition potentials since the smaller critical clusters favor forming fcc nuclei. The critical clusters formed at a fixed potential can have a distribution in size and the size distribution can shift to smaller sizes when the potential value increases. At -1.6V, the sizes of all critical clusters can be large enough to form hcp nuclei. At -2.0V and 2.5V, a part of critical clusters can be smaller in size and can be transformed into fcc nuclei. At -3.0V, all critical clusters can be small in size enough to form fcc nuclei.

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